**NT OR PW PACKAGE** 

SCES610 - OCTOBER 2004

- 2-V to 5.5-V V<sub>CC</sub> Operation
- Max t<sub>pd</sub> of 15 ns at 5 V
- **Schmitt-Trigger Inputs Allow for Slow Input** Rise/Fall Time
- Polarity Control for Y Outputs Selects True or Complementary Logic
- Typical V<sub>OLP</sub> (Output Ground Bounce) <0.8 V at  $V_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot)  $>2.3 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Ioff Supports Partial-Power-Down Mode Operation
- **Supports Mixed-Mode Voltage Operation on All Ports**
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- **ESD Protection Exceeds JESD 22** 
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

#### (TOP VIEW) 24 🛮 V<sub>CC</sub> T/C 23 P Α 🛮 B [] 3 22 N 21 Y1 D1 | 4 20 TY2 D2 | 5 рз Г 6 19 **∏** Y3 D4 [] 7 18 **∏** Y4 17 Y5 D5 🛮 8 D6 [] 9 16 Y6 D7 ∏ 10 15 ∏ Y7 14 Y8 D8 [] 11 13 OE **GND** | 12

#### description/ordering information

The SN74LV8151 is a 10-bit universal Schmitt-trigger buffer with 3-state outputs, designed for 2-V to 5.5-V  $m V_{CC}$ operation. The logic control ( $\overline{\Gamma/C}$ ) pin allows the user to configure Y1 to Y8 as noninverting or inverting outputs. When  $T/\overline{C}$  is high, the Y outputs are noninverted (true logic), and when  $T/\overline{C}$  is low, the Y outputs are inverted (complementary logic).

When output-enable (OE) input is low, the device passes data from Dn to Yn. When OE is high, the Y outputs are in the high-impedance state. The path A to P is a simple Schmitt-trigger buffer, and the path B to N is a simple Schmitt-trigger inverter.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

To ensure the high-impedance state during power up or power down, OE should be tied to VCC through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

#### ORDERING INFORMATION

TA	PACKAGE <sup>†</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP – NT	Tube	SN74LV8151NT	SN74LV8151NT
-40°C to 85°C	TOOOD DW	Tube	SN74LV8151PW	11/0454
	TSSOP – PW	Tape and reel	SN74LV8151PWR	LV8151

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



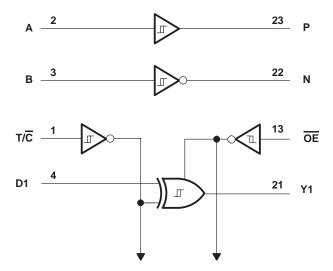
#### **FUNCTION TABLES**

INPUT A	OUTPUT P
L	L
Н	Н

INPUT B	OUTPUT N
L	Н
Н	L

	INPUTS			
OE	T/C	D	Y	
L	L	L	Н	
L	L	Н	L	
L	Н	L	L	
L	Н	Н	Н	
Н	X	X	Z	

# logic diagram



To Seven Other Channels

## SN74LV8151 10-BIT UNIVERSAL SCHMITT-TRIGGER BUFFER WITH 3-STATE OUTPUTS

SCES610 - OCTOBER 2004

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>	–0.5 V to 7 V
Input voltage range, V <sub>I</sub> (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high-impedance	
or power-off state, V <sub>O</sub> (see Note 1)	–0.5 V to 7 V
Output voltage range, VO (see Notes 1 and 2)	0.5 V to V <sub>CC</sub> + 0.5 V
Input clamp current, $I_{IK}$ ( $V_I < 0$ )	
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	–50 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$	±35 mA
Continuous current through V <sub>CC</sub> or GND	±70 mA
Package thermal impedance, $\theta_{JA}$ (see Note 3): NT package	67°C/W
(see Note 4): PW package	
Storage temperature range, T <sub>stq</sub>	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. This value is limited to 5.5 V maximum.
- 3. The package thermal impedance is calculated in accordance with JESD 51-3.
- 4. The package thermal impedance is calculated in accordance with JESD 51-7.



# SN74LV8151 10-BIT UNIVERSAL SCHMITT-TRIGGER BUFFER WITH 3-STATE OUTPUTS

SCES610 - OCTOBER 2004

## recommended operating conditions (see Note 5)

			VCC	MIN	MAX	UNIT
Vcc	Supply voltage			2	5.5	V
		[		1.5		
.,	High lavel input value of		2.3 V to 2.7 V	V <sub>CC</sub> ×0.7		V
VIΗ	High-level input voltage		3 V to 3.6 V	V <sub>CC</sub> ×0.7		V
			4.5 V to 5.5 V	V <sub>CC</sub> ×0.7		
			2 V		0.5	
V	Law lawal input valtage		2.3 V to 2.7 V		$V_{CC} \times 0.3$	V
VIL	Low-level input voltage	w-level input voltage  w-level input voltage  aut voltage  High or low state 3-state  gh-level output current  w-level output current  T/C, OE inputs  A, B, D inputs	3 V to 3.6 V		$V_{CC} \times 0.3$	V
			4.5 V to 5.5 V		$V_{CC} \times 0.3$	
$\vee_{I}$	Input voltage			0	5.5	V
\	Outrotockon	High or low state		0	VCC	V
۷O	Output voltage	3-state		0		V
			2 V		-50	μΑ
	$V_{O} \qquad \text{Output voltage} \qquad \qquad \frac{\text{High or low state}}{3\text{-state}}$ $I_{OH} \qquad \text{High-level output current}$ $I_{OL} \qquad \text{Low-level output current}$ $\frac{T/\overline{C}, \ \overline{OE} \ \text{inputs}}{}$ $\Delta t/\Delta v \qquad \text{Input transition rise or fall rate}$		2.3 V to 2.7 V		-2	
ЮН		3 V to 3.6 V		-6	mA	
			4.5 V to 5.5 V	1.5 7 V VCC × 0.7 8 V VCC 9 VCC 9 0 9 0 9 0 1.5 V VCC 9 0 9 0 9 0 9 0 9 0 9 0 9 0 9 0 9 0 9 0	-12	
			2 V		50	μΑ
	Law law law at autout au mant		2.3 V to 2.7 V		2	
IOL	Low-level output current		3 V to 3.6 V		6	mA
			4.5 V to 5.5 V		12	
			2.3 V to 2.7 V		200	
10H   High-level output current   2.3 V to 3   4.5 V to 3   2 V   2.3 V to 3   4.5 V to 3   4.	3 V to 3.6 V		100	ns/V		
		4.5 V to 5.5 V		20		
ΔÜΔV	input transition rise or fall rate		2.3 V to 2.7 V		4	
		A, B, D inputs	3 V to 3.6 V		3	ms/V
			4.5 V to 5.5 V		2	
TA	Operating free-air temperature			-40	85	°C

NOTES: 5. All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	v <sub>cc</sub>	MIN	TYP	MAX	UNIT	
V <sub>T+</sub>		2.5 V			1.75		
Positive-going input	A, B, and D inputs	3.3 V			2.31	V	
threshold voltage		5 V			3.5		
V <sub>T</sub> _		2.5 V	0.75				
Negative-going input	A, B, and D inputs	3.3 V	0.99			V	
threshold voltage		5 V	1.5				
ΔVΤ		2.5 V	0.25		1		
Hysteresis	A, B, and D inputs	3.3 V	0.33		1.32	V	
$(V_{T+} - V_{T-})$		5 V	0.5		2		
	I <sub>OH</sub> = -50 μA	2 V to 5.5 V	V <sub>CC</sub> - 0.1			٧	
<u></u>	$I_{OH} = -2 \text{ mA}$	2.3 V	2				
VOH	I <sub>OH</sub> = -6 mA	3 V	2.48			V	
	I <sub>OH</sub> = -12 mA	4.5 V	3.8				
	I <sub>OL</sub> = 50 μA	2 V to 5.5 V			0.1		
<u></u>	I <sub>OL</sub> = 2 mA	2.3 V			0.4	.,	
VOL	I <sub>OL</sub> = 6 mA	3 V			0.44	V	
	I <sub>OL</sub> = 12 mA	4.5 V			0.55		
I <sub>I</sub>	V <sub>I</sub> = 5.5 V or GND	0 to 5.5 V			±1	μΑ	
I <sub>OZ</sub>	$V_O = V_{CC}$ or GND	5.5 V			±5	μΑ	
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			20	μΑ	
l <sub>off</sub>	$V_I$ or $V_O = 0$ to 5.5 $V$	0			5	μΑ	
	V V 0ND	3.3 V		3		_	
Ci	$V_I = V_{CC}$ or GND	5 V		3		pF	
		3.3 V		5		_	
Co	VO = VCC or GND	5 V		5		pF	

# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 2.5 V $\pm$ 0.2 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T <sub>A</sub> = 25°C	MIN	MAX	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	TYP	IVIIIN	IVIAA	UNIT	
	A or B	P or N		22	1	45		
t <sub>pd</sub>	D	V		23	1	49	ns	
·	T/C	Y	$C_{I} = 15  pF$	24	1	50		
t <sub>en</sub>	ŌĒ	Υ	C <sub>L</sub> = 15 pF	]	12	1	25	ns
t <sub>dis</sub>	ŌE	Υ		11	1	20	ns	
	A or B	P or N		26	1	52		
tpd	D	V	]	28	1	57	ns	
	T/C	Y	$C_{L} = 50 \text{ pF}$	29	1	58		
t <sub>en</sub>	ŌE	Υ	. остори	15	1	30	ns	
<sup>t</sup> dis	ŌĒ	Υ		15	1	26	ns	



# SN74LV8151 10-BIT UNIVERSAL SCHMITT-TRIGGER BUFFER WITH 3-STATE OUTPUTS

SCES610 - OCTOBER 2004

# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 3.3 V $\pm$ 0.3 V (unless otherwise noted) (see Figure 1)

DADAMETER	FROM	то	LOAD	T <sub>A</sub> = 25°C		MAN	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITA NCE	TYP	MIN	MAX	UNIT
	A or B	P or N		14	1	26	
<sup>t</sup> pd	D	V	C <sub>L</sub> = 15 pF	15	1	29	ns
	T/C	Υ		16	1	30	
t <sub>en</sub>	ŌĒ	Υ		9	1	16	ns
<sup>t</sup> dis	ŌE	Υ		8	1	14	ns
	A or B	P or N		17	1	32	
<sup>t</sup> pd	D	Y C <sub>1</sub> = 5		18	1	34	ns
F	T/C		C <sub>L</sub> = 50 pF	20	1	36	
t <sub>en</sub>	ŌE	Υ		11	1	20	ns
<sup>t</sup> dis	ŌĒ	Υ	]	11	1	18	ns

# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 5 V $\pm$ 0.5 V (unless otherwise noted) (see Figure 1)

242445	FROM	то	LOAD	T <sub>A</sub> = 25°C						
PARAMETER	(INPUT)	(OUTPUT)	CAPACITA NCE	TYP	MIN	MAX	UNIT			
	A or B	P or N		9	1	15				
<sup>t</sup> pd	D	V	Y		ĺ		10	1	16	ns
	T/C	Y		11	1	17				
t <sub>en</sub>	ŌĒ	Υ		6	1	10.5	ns			
<sup>t</sup> dis	ŌE	Υ		6	1	10	ns			
	A or B	P or N		11	1	18				
<sup>t</sup> pd	D	V	Y C <sub>L</sub> = 50 pF	12	1	20	ns			
	T/C	Y		13	1	21				
t <sub>en</sub>	ŌĒ	Y		8	1	12.5	ns			
<sup>t</sup> dis	ŌĒ	Υ		8	1	11.5	ns			

# noise characteristics, $V_{CC} = 3.3 \text{ V}$ , $C_L = 50 \text{ pF}$ (see Note 6)

	PARAMETER		T <sub>A</sub> = 25°C		
			TYP	MAX	UNIT
VOL(P)	Quiet output, maximum dynamic V <sub>OL</sub>		0.6		V
V <sub>OL(V)</sub>	Quiet output, minimum dynamic V <sub>OL</sub>		-0.6		V
V <sub>OH(V)</sub>	Quiet output, minimum dynamic V <sub>OH</sub>		2.9		V
V <sub>IH(D)</sub>	High-level dynamic input voltage	2.31			V
V <sub>IL(D)</sub>	Low-level dynamic input voltage			0.99	V

NOTE 6: Characteristics are for surface-mount packages only.

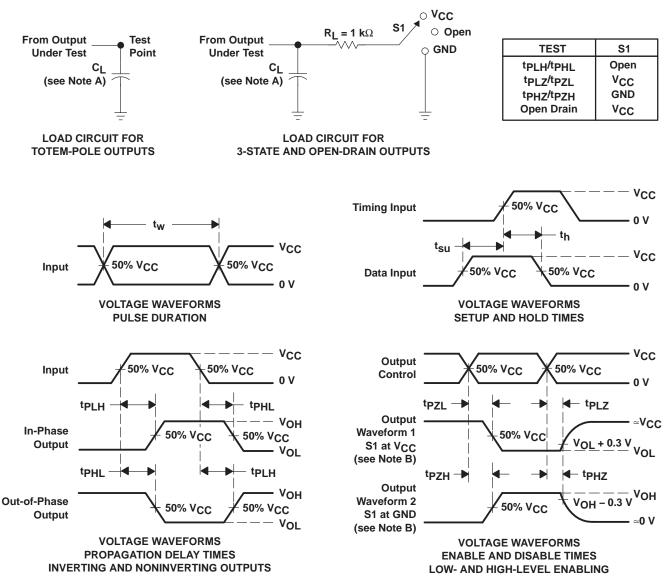


# SN74LV8151 10-BIT UNIVERSAL SCHMITT-TRIGGER BUFFER WITH 3-STATE OUTPUTS SCES610 - OCTOBER 2004

# operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	VCC         TYP           3.3 V         15		UNIT
C . Dower dissination conssituace	Cı = No load. f = 1 MHz	3.3 V		PΓ	
Cpd	Power dissipation capacitance	$C_L = No load, f = 1 MHz$	5 V	16	рг

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq 3$  ns,  $t_f \leq 3$  ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpHL and tpLH are the same as tpd.
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms







11-Apr-2013

### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
SN74LV8151DGVR	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV8151	Samples
SN74LV8151DGVRE4	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV8151	Samples
SN74LV8151DGVRG4	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV8151	Samples
SN74LV8151DW	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV8151	Samples
SN74LV8151DWE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV8151	Samples
SN74LV8151DWG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV8151	Samples
SN74LV8151DWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV8151	Samples
SN74LV8151DWRE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV8151	Samples
SN74LV8151DWRG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV8151	Samples
SN74LV8151NT	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	SN74LV8151NT	Samples
SN74LV8151NTE4	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	SN74LV8151NT	Samples
SN74LV8151PW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV8151	Samples
SN74LV8151PWE4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV8151	Samples
SN74LV8151PWG4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV8151	Samples
SN74LV8151PWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV8151	Samples
SN74LV8151PWRE4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV8151	Samples
SN74LV8151PWRG4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV8151	Samples



## PACKAGE OPTION ADDENDUM

11-Apr-2013

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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# PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV8151DGVR	TVSOP	DGV	24	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV8151DWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1

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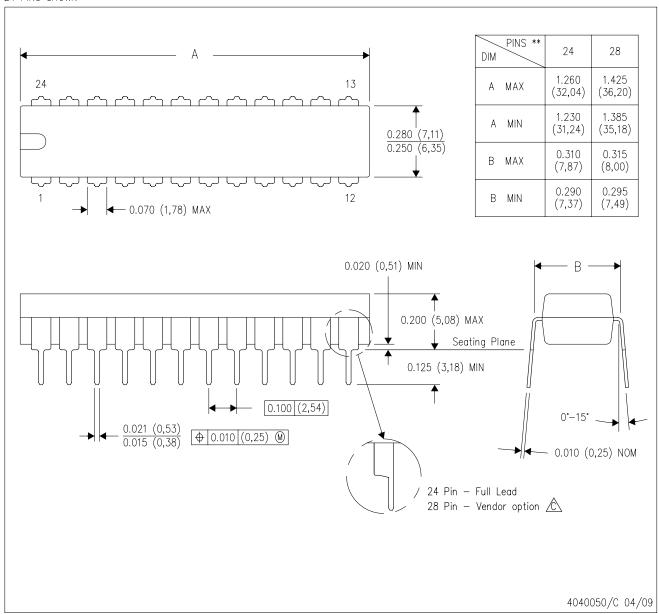
#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins SPQ		Length (mm)	Width (mm)	Height (mm)	
SN74LV8151DGVR	TVSOP	DGV	24	2000	367.0	367.0	35.0	
SN74LV8151DWR	SOIC	DW	24	2000	367.0	367.0	45.0	

# NT (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

The 28 pin end lead shoulder width is a vendor option, either half or full width.



## DGV (R-PDSO-G\*\*)

#### **24 PINS SHOWN**

#### **PLASTIC SMALL-OUTLINE**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194 DW (R-PDSO-G24)

# PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



PW (R-PDSO-G24)

## PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G24)

# PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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